

AH9280

#### Two Phase Dual-coil High Voltage Smart Fan Motor Driver

#### **General Description**

The AH9280 is a most advanced smart fan controller and Hall IC driver manufactured by special CMOS process. It is designed for 5V and 12V cooling fan. To allow survival in a harsh environment and lower the total system cost, the AH9280 has been designed with many powerful functions while almost eliminating all discrete components, such as, capacitor, resistor, transistor, diode and PC board.

The AH9280 can operate normally in an ambient temperature up to 125°C due to its Hall IC circuitry and power MOSFET output that allow low power dissipation.

When there is no motion for one second, the IC will automatically detect the locked rotor conditions, and enter protection mode, shutting off the motor driver for five seconds. Then, the IC will turn on the motor driver for one second to detect whether there is rotation condition, if fails, the IC will shut off motor driver for five seconds again. This sequence will be repeated until rotation condition is detected, and the IC enters normal operation. This feature can effectively prevent the AH9280 from overheating and damage due to long-time locked rotor condition.

Specially designed for driving large fans, the AH9280 is optimized for low start-up voltage.

The AH9280 is available in TO-94 package.

#### Features

- High-sensitivity Integrated Hall Sensor
- Low Start-up Voltage
- 5V and 12V Operation
- Peak Output Current up to 1200mA
- Power-efficient CMOS and Power MOSFETs
- Built-in Output Protection Clamping Diode
- Locked Rotor Shutdown and Auto-restart
- ESD Rating: 6000V (Human Body Model) 400V (Machine Model)

#### **Applications**

- 5V/12V DC Brushless Motor/Fan
- PC, Server, Laptop Cooling Fan
- Power Supply Cooling Fan
- Large/Small Sized Fan







# **Pin Configuration**



Figure 2. Pin Configuration of AH9280 (Front View)

# **Pin Description**

Pin Number	Pin Name	Function
1	VCC	Power supply pin
2	DO	Output pin 1
3	DOB	Output pin 2
4	GND	Ground pin



#### AH9280

## **Functional Block Diagram**



Figure 3. Functional Block Diagram of AH9280

## **Ordering Information**



Package	Temperature Range	Part Number	Marking ID	Packing Type	
TO-94	-40 to 125°C	AH9280Z4-G1	9280Z4-G1	Bulk	

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.

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## Absolute Maximum Ratings (Note 1, T<sub>A</sub>=25°C)

Parameter	Symbol	Value	Unit
Supply Voltage	V <sub>CC</sub>	18	V
Peak Output Current	I <sub>OUT_P</sub>	1200	mA
Continuous Output Current	I <sub>OUT_C</sub>	600	mA
Supply Current (Fault)	I <sub>CC</sub>	6	mA
Power Dissipation	P <sub>D</sub>	600	mW
Thermal Resistance (Junction to Ambient)	$\theta_{JA}$	208	°C/W
Storage Temperature	T <sub>STG</sub>	-55 to 150	°C
ESD (Human Body Model)	ESD	6000	V
ESD (Machine Model)	ESD	400	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

## **Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V <sub>CC</sub>	2.5	16	V
Ambient Temperature	T <sub>A</sub>	-40	125	°C



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### **Electrical Characteristics**

$\mathbf{V} = 10\mathbf{V}\mathbf{T}$	-2500	1	- 41	: C: 1
$V_{CC}$ =12V, $T_A$	=23°C,	unless	otherwise	specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	V <sub>CC</sub>	Operating	2.5	12	16	V
Supply Current	I <sub>CC</sub>	Average		4	6	mA
Output Current	I <sub>OUT</sub>				500	mA
Output Leakage Current	I <sub>LEAKAGE</sub>			0.1	10	μΑ
Saturation Voltage	V <sub>SAT</sub>	I <sub>OUT</sub> =350mA		600	1000	mV
Output On Time	T <sub>ON</sub>			0.8		S
Output Off Time	T <sub>OFF</sub>			5		S
Output Zener Break-down Voltage	Vz			35		V

## **Magnetic Characteristics**

 $V_{CC}$ =12V,  $T_A$ =25°C, unless otherwise specified.

Parameter	Symbol	Min	Тур	Max	Unit
Operating Point	B <sub>OP</sub>		20	50	Gauss
Releasing Point	B <sub>RP</sub>	-50	-20		Gauss
Hysteresis	B <sub>HYS</sub>		40		Gauss



Magnetic Flux Density (Gauss)



### **Test Circuit**



Figure 4. Basic Test Circuit of AH9280





Figure 6.  $V_{DOB}$  vs. Magnetic Flux Density



## **Typical Performance Characteristics**



Figure 7. Supply Current vs. Supply Voltage



Figure 8. Supply Current vs. Ambient Temperature



Figure 9.  $B_{\text{OP}}/B_{\text{RP}}/B_{\text{HYS}}\,vs.$  Supply Voltage



Figure 10. Saturation Voltage vs. Ambient Temperature



**Typical Performance Characteristics (Continued)** 





Figure 11. Saturation Voltage vs. Output Current

Figure 12. Power Dissipation vs. Ambient Temperature



Figure 13. BOP/BRP/BHYS vs. Ambient Temperature

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## **Typical Application**



Figure 14 Typical Application 1 of AH9280 (Note 2)

Note 2:

1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.

2. R1=47 $\Omega$  typical.

3. C1=C2=C3=2.2 $\mu$ F typical, electrolytic capacitors are better. They should be fine tuned based on system design.

4. R2=R3=4.7 $\Omega$  typical. They can be removed according to system requirement.



# **Typical Application (Continued)**



Figure 15. Typical Application 2 of AH9280 (Note 3)

Note 3:

- 1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.
- 2. R1=47 $\Omega$  typical.
- 3. C1 =  $2.2\mu$ F typical, electrolytic capacitors are better. They should be fine tuned based on system design.
- 4. ZD1 and ZD2 breakdown voltage are 35V.



**TO-94** 

#### **Mechanical Dimensions**

Unit: mm(inch)





#### **BCD Semiconductor Manufacturing Limited**

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